

Product Features

- 900 ~ 930MHz
- 1500W CW Peak Power @ 50V
- 63% Drain Efficiency @ 50V
- Low Cost, Light Weight, Compact
- Using GaN-on-SiC HEMT Transistor
- Excellent Thermal Stability and Ruggedness
- Externally 50Ω Matched

Applications

- High Power Industry
- Microwave CVD Reactor
- Plasma Generator
- Food Science
- MW Heating and Drying



Description

RIM091K5-20 using GaN-on-SiC transistors is designed for industrial, scientific, medical (ISM) and plasma applications at 915MHz. RIM091K5-20 is the world's highest power and efficiency SSPA with affordable price. This amplifier is suitable for use in CW, ISM applications. This high efficiency rugged device is targeted to replace industrial magnetrons and other vacuum tubes which are currently applying into high power industrial applications, artificial diamond manufacturing, semiconductor equipments, and plasma systems.

Electrical Specifications @ V_{DS} =50V, T=25°C, 50Ω System

P	ARAMETER	UNIT	MIN	TYP	MAX	SYMBOL
Operating Frequency		MHz	900	-	930	Fo
Operating Bandwidth		MHz	-	30	-	OBW
CW Output Power		W	-	1500	-	Po
Efficiency		%	-	63	-	Eff
Input Power		dBm	-	10	-	P _I
Power Gain @ Peak Power		dB	-	51.8	-	$G_{\mathbb{P}}$
Gain Flatness		dB	-	0.5	1.0	ΔG_{P}
In/Out Return Loss		dB	-	-	-15	S ₁₁
Operating Voltage		V	-	50	-	Vdc
Operating Case Temperature			-	-	60	Тс
	DCM21HA4PNK87	A1~A4	A1~A2(50V ±1%), A3~A4(GND)			
		1~2	+12V±5%			
		3	Input Power Monitor			
		4	RF En/Dis: Enable(Low), Disable(High or Open)			
		5	+50V DC Voltage Monitor			
DC &		8	Gain Control			
Controls Connector		9	GND			
		10~11	10(Current Monitor_A), 11(Current Monitor_B)			
		14~15	14(Temp Monitor_A), 15(Temp Monitor_B)			
		16	Reflect Power Monitor			
		17	Forward Power Monitor			
		Others	Reserved			

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All specifications may change without notice Version 1.0



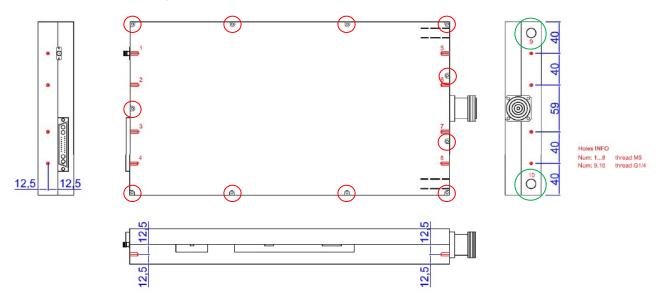
Mechanical Specifications

PARAMETER	UNIT	VALUE	
Dimensions (L x W x H)	mm	400 x 219 x 45	
Weight	Kg	7.0 typ	
RF Input Connectors	-	SMA, Female	
RF Output Connectors		7/16 DIN, Female	
DC & I/O Connector	-	DCM21HA4PNK87	
Cooling	-	Water cooling (20°C typ, 2 liter per minute, 0.2 bar)	

Note

Water cooling condition may be subject to change.

Mechanical drawing



: Mount Hole
: Water Inlet/Outlet

GaN Solid State Power Amplifier

RIM091K5-20



Revision History

Part Number	Release Date	Version	Description	Data Sheet Status
RIM091K5-20	2020.09.11	1.0	Release of Datasheet	Production

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